NSN 5961-01-112-8088

Demilitarization:

No Fiig: A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-112-8088 **Inclosure Material:** Plastic and metal **Overall Length:** Between 0.560 inches and 0.650 inches **Terminal Length:** Between 0.500 inches and 0.580 inches Overall Width: Between 0.380 inches and 0.420 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-22oab **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 collector to emitter voltage, dc with specified circuit between base and emitter and 40.0 emitter to base voltage, static, collector open and 5.0 collector to base voltage/static/emitter open **Current Rating Per Characteristic:** 8.00 amperes source cutoff current and 0.25 amperes source cutoff current **Power Rating Per Characteristic:** 65.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 1000.0 static forward current transfer ratio, common-emitter and 20000.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release 6420 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:**